



Datasheet

Nichia NDG7D75

Absolute Maximum Ratings

Item	Condition	Symbol	Rating	Unit
Forward Current	T _{Case} =25°C	I _f	2300	mA
Allowable Reverse Current	T _{Case} =25°C	l _r	85	mA
Raw Diode Operating Temperature*	-	T _{Case}	0 to +60	°C
Raw Diode Storage Temperature*	-	T _{Storage}	-40 to +85	°C

Operation outside these conditions may damage the device. Operation at maximum ratings influence lifetime.

Optical and Electrical Characteristics

Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Optical Output Power	I _f =1.9A	Po	-	1400	-	mW
Optical Output Power	Pulsed *1	Po	-	-	-	mW
Dominant Wavelength	I _f =1.9A	λ_{d}	518	525	532	nm
Threshold Current	CW	l _{th}	150	280	500	mA
Operating Current	CW	l _{op}	-	1900	-	mA
Operating Current	Pulsed *1	l _p	-	-	-	А
Operating Voltage	I _f =1.9A	U _{op}	4.0	4.7	5.5	V
Slope Efficiency	CW	η	0.5	1.0	1.4	W/A
Raw Diode Beam Divergence (1/e²)	I _f =1.9A	θ	5	8.2	25	deg
	I _f =1.9A	θ_	30	40	50	deg
Beam Size	Without Correction	-	-	0.6 x 2.7	-	mm
Beam Size	With Correction	-	-	3.1 x 2.7	-	mm
Beam Divergence (full angle)	Without Correction	-	-	3.5	-	mrad
Beam Divergence (full angle)	With Correction	-	-	0.85	-	mrad
Heatsink Temperature Range *2	With TEC (T _c =25°C)	Т	-20	-	70	°C
Power Consumption *2	Without TEC	P _{el}	-	9	-	W
Power Consumption *2	With TEC	P _{el}	-	50	-	W

^{*}¹ Pulse Condition: Pulse frequency \geq 50Hz, Duty \leq 33%

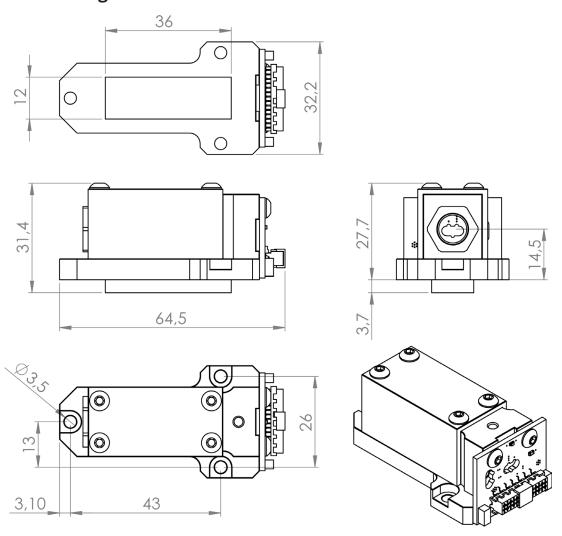
Attention: Use an appropriately sized heatsink and mount module with supplied thermal compound.

^{*} Temperature measured at diode backplate

^{*2} with ColorDRIVE one, V_{in} = +10 to 24 V_{DC}



Technical Drawings



Images



Contact

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